## TOSHIBA BiCD Integrated Circuit Silicon Monolithic

## TB62269FTAG

## PWM method CLK-IN bipolar stepping motor driver

The TB62269FTAG is a PWM chopper type clock-in controlled motor driver for two-phase bipolar stepping motor. Fabricated with the BiCD process, the TB62269FTAG is rated at $40 \mathrm{~V} / 1.8 \mathrm{~A}$
The internal voltage regulator allows control of the motor with a single VM power supply.

## Features

- Bipolar stepping motor driver
- PWM controlled constant-current drive
- Clock input control

- Allows full, half, quarter , $1 / 8,1 / 16$, and $1 / 32$ step resolutions
- Low on-resistance of output stage by using BiCD process
- High Voltage and large current (For specification, please refer to absolute maximum ratings and operation ranges.)
- Thermal shutdown (TSD), over-current shutdown (ISD), and power-on reset (POR)
- Built-in regulator allows the TB62269FTAG to operate with only VM power supply.
- Able to customize chopping frequency by external resistance and capacitor.
- Packages: P-VQFN32-0505-0.50-004

[^0]
## 1. Pin assignment

(Top View)


## 2. Block Diagram



Functional blocks, circuit, and constants etc. in the block diagram may be omitted or simplified for explanatory purposes.

Note: For GND wiring, we recommend that a heat sink should be grounded at all points, and the board should be grounded at only one GND pin for single point ground.
Careful attention should be paid to the layout of the output, VM and GND traces, to avoid short circuits across output pins or to the power supply or ground. If such a short circuit occurs, the TB62269FTAG may be permanently damaged.
Also, the utmost care should be taken for pattern designing and implementation of the TB62269FTAG since it has power supply pins (VM, RS, OUT, and GND) through which a particularly large current may run. If these pins are wired incorrectly, an operation error may occur or the TB62269FTAG may be destroyed.
The logic input pins must also be wired correctly. Otherwise, the TB62269FTAG may be damaged owing to a current running through the IC that is larger than the specified current.

## 3. Pin Function

## TB62269FTAG (QFN32)

Function explanation of terminal number 1 to 32

| Pin No. | Pin Name | Function | Pin No. | Pin Name | Function |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | CLK_IN | An electrical angle leads on the rising edge of the clock input. A motor rotation count depends on the input frequency. | 17 | OUT_B2 | B-channel output+ |
| 2 | ENABLE | A, B-channel output enable (5V) OFF switching pin (GND) | 18 | OUT_B1 |  |
| 3 | RESET | Electric angle reset | 19 | RS_B2 | A sensing resistance connection pin for a current value setting of B-channel output |
| 4 | GND | Logic ground | 20 | RS_B1 |  |
| 5 | RS_A1 | A sensing resistance connection pin for a current value setting of A-channel output | 21 | VM | Monitoring pin of motor power supply |
| 6 | RS_A2 |  | 22 | NC | No-connect |
| 7 | OUT_A1 | A-channel output+ | 23 | VCC | Monitoring pin for internal generation 5V bias |
| 8 | OUT_A2 |  | 24 | L_OUT | Error detect signal output pin |
| 9 | GND | Power GND of A-channel | 25 | D_MODE0 | Step resolution mode control 0 |
| 10 | OUT_A1- | A-channel output- | 26 | GND | Logic ground |
| 11 | OUT_A2- |  | 27 | VREF | Bias pin for tuning the current level |
| 12 | GND | Power GND of A-channel | 28 | OSCM | Oscillator pin for PWM chopper |
| 13 | GND | Power GND of A-channel | 29 | CW/CCW | Motor rotation: forward/reverse |
| 14 | OUT_B2- | B-channel output- | 30 | MO_OUT | Electric angle monitor pin |
| 15 | OUT_B1- |  | 31 | D_MODE1 | Step resolution mode control pin 1 |
| 16 | GND | Power GND of B-channel | 32 | D_MODE2 | Step resolution mode control pin 2 |

- Please use the pin of NC with Open.
- Please connect the pins with the same names, at the nearest point of the device.


## 4. Input equivalent circuit

## TB62269FTAG



The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

| Pin No | Pin name |
| :--- | :--- |
| 1 | CLK_IN |
| 2 | ENABLE |
| 3 | RESET |
| 5,6 | RS_A |
| 7,8 | OUT_A |
| 10,11 | OUT_A- |
| 14,15 | OUT_B- |
| 17,18 | OUT_B |
| 19,20 | RS_B |
| 21 | VM |
| 23 | VCC |
| 24 | L_OUT |
| 25 | D_MODE0 |
| 27 | VREF |
| 28 | OSCM |
| 29 | CW/CCW |
| 30 | MO_OUT |
| 31 | D_MODE1 |
| 32 | D_MODE2 |
|  |  |

## 5. CLK Function

The electrical angle leads one by one in the manner of the clocks. The clock signal is reflected to the electrical angle on the rising edge.

| CLK Input | Function |
| :---: | :--- |
| Rise | The electrical angle leads one by one on the rising edge. |
| Fall | - (Remains at the same position.) |

## 6. ENABLE Function

The ENABLE pin controls whether the current is allowed to flow through a given phase for a stepper motor drive. This pin selects whether the motor is stopped in OFF mode (high impedance state: Z) or activated. The pin must be fixed to Low at power-on or power-down.

| ENABLE Input | Function |
| :---: | :--- |
| H | Output transistors are enabled (normal operation). |
| L | Output transistors are disabled (high impedance state: Z ). |

## 7. CWICCW Function

The CW/CCW pin switches rotation direction of stepper motors.

| CW/CCW Input | Function | OUT (+) | OUT (-) |
| :---: | :---: | :---: | :---: |
| H | Clock-wise | H | L |
| L | Counter clock-wise | L | H |

8. Step resolution Mode Select Function

| D_MODE0 | D_MODE1 | D_MODE2 | Function |
| :---: | :---: | :---: | :---: |
| L | L | L | STANDBY MODE <br> (OSCM stop, output transistors are disabled, full step mode, torque 100\%) |
| L | L | H | Full step |
| L | H | L | Half step(a) |
| L | H | H | Quarter step |
| H | L | L | Half step(b) |
| H | L | H | $1 / 8$ step |
| H | H | L | $1 / 16$ step |
| H | H | H | $1 / 32$ step |

It is recommended that D_MODE0, D_MODE1 and D_MODE2 are changed after setting RESET to Low in the state of an initial state (MO_OUT = Low).

## 9. RESET Function

| RESET Input | Function |
| :---: | :---: |
| L | Normal operation mode |
| H | The electrical angle is reset. |

Phase currents when RESET is applied are as follows:
In this case, the terminal MO_OUT becomes Low.

| Step resolution <br> mode | A-channel <br> current | B-channel <br> current | Electric <br> Angle |
| :---: | :---: | :---: | :---: |
| Full step | $100 \%$ | $100 \%$ | $45^{\circ}$ |
| Half step | $100 \%$ | $100 \%$ | $45^{\circ}$ |
| Quarter step | $71 \%$ | $71 \%$ | $45^{\circ}$ |
| $1 / 8$ step | $71 \%$ | $71 \%$ | $45^{\circ}$ |
| $1 / 16$ step | $71 \%$ | $71 \%$ | $45^{\circ}$ |
| $1 / 32$ step | $71 \%$ | $71 \%$ | $45^{\circ}$ |

## 10. Output function of reset signal

When IC is stopped by applying Thermal shutdown(TSD) or Over-current shutdown(ISD), Low is output.


It is an open-drain output. When the output pin is pulled up with a resistor to power supply, Low is output (internal ON) at the time of Reset. Then High (internal Hi-Z) is output in normal operation (no-Reset).
Pull-up to VCC pin.

## 11. Absolute Maximum Ratings ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Rating | Unit | Remarks |
| :--- | :---: | :---: | :---: | :---: |
| Motor power supply | $\mathrm{V}_{\mathrm{M}}$ | 40 | V |  |
| Motor output voltage | $\mathrm{V}_{\text {OUT }}$ | 40 | V |  |
| Motor output current | $\mathrm{I}_{\text {OUT }}$ | 1.8 | $\mathrm{~A} / \mathrm{phase}$ | Note 1 |
| Logic power supply | $\mathrm{V}_{\mathrm{CC}}$ | 6.0 | V | When externally applied. |
| Digital input voltage | $\mathrm{V}_{\text {IN }}$ | 6.0 | V |  |
| MO,L_OUT output voltage | $\mathrm{V}_{\text {MO }}, \mathrm{V}_{\mathrm{L} \_ \text {out }}$ | 6.0 | V |  |
| MO,L_OUT Inflow current | $\mathrm{I}_{\text {MO }}, \mathrm{I}_{\mathrm{L} \_ \text {OUT }}$ | 30.0 | mA |  |
| Power dissipation | $\mathrm{P}_{\mathrm{D}}$ | 1.3 | W | Note 2 |
| Operating temperature | $\mathrm{T}_{\text {opr }}$ | -20 to 85 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage temperature | $\mathrm{T}_{\text {str }}$ | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Junction temperature | $\mathrm{T}_{\mathrm{j}(\mathrm{Max})}$ | 150 | ${ }^{\circ} \mathrm{C}$ |  |

Note 1: As a guide, the maximum output current should be kept below 1.4 A per phase. The maximum output current may be further limited in view of thermal considerations, depending on ambient temperature and board conditions.

Note 2: Stand-alone $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$
When Ta exceeds $25^{\circ} \mathrm{C}$, it is necessary to do the derating with $10.4 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$.
$\mathrm{Ta}:$ Ambient temperature
Topr: Ambient temperature while the TB62269FTAG is active
Tj : Junction temperature while the TB62269FTAG is active. The maximum junction temperature is limited by the thermal shutdown (TSD) circuitry. It is advisable to keep the maximum current below a certain level so that the maximum junction temperature, Tj (MAX), will not exceed $120^{\circ} \mathrm{C}$.

## Caution: Absolute maximum ratings

The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.
Exceeding the rating (s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.
The value of even one parameter of the absolute maximum ratings should not be exceeded under any circumstances. The TB62269FTAG does not have overvoltage detection circuit. Therefore, the device is damaged if a voltage exceeding its rated maximum is applied.

All voltage ratings, including supply voltages, must always be followed. The other notes and considerations described later should also be referred to.

## 12. Operation Ranges ( $\mathrm{Ta}=0$ to $85^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Min | Typ. | Max | Unit | Remarks |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Sensing resistance connection pin voltage | $V_{\text {RS }}$ | 0.0 | $\pm 1.0$ | $\pm 1.5$ | V | VM terminal standard,(Note 2) |
| Motor power supply | $\mathrm{V}_{\mathrm{M}}$ | 10.0 | 24.0 | 38.0 | V |  |
| Motor output current | lout | - | 1.4 | 1.8 | A | 1 phase, (Note 1) |
| Logic input voltage | $\mathrm{V}_{\operatorname{IN}(\mathrm{H})}$ | 2.0 | - | 5.5 | V | H-level of the logic |
|  | $\mathrm{V}_{\text {IN(L) }}$ | -0.4 | - | 1.0 | V | L-level of the logic |
| MO output pin voltage | $\mathrm{V}_{\text {MO, }} \mathrm{V}_{\text {L_OUT }}$ | - | 3.3 | 5.5 | V | The voltage of pull-up direction |
| Clock input frequency | $\mathrm{f}_{\text {CLK }}$ | - | - | 100 | kHz |  |
| Chopper frequency | $\mathrm{f}_{\text {chop }}$ | 40 | 100 | 150 | kHz |  |
| $\mathrm{V}_{\text {ref }}$ reference voltage | $\mathrm{V}_{\text {ref }}$ | GND | - | 3.6 | V |  |

Note 1: Maximum current for actual usage may be limited by the operating circumstances such as operating conditions (step resolution mode, operating time, and so on), ambient temperature, and heat conditions (board condition and so on).
Note 2: Maximum voltage of $\mathrm{V}_{\mathrm{RS}}$ must not be exceeded the absolute maximum rating.

## 13. Electrical Characteristics

## 13-1. Electrical Characteristics $1\left(\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{VM}=24 \mathrm{~V}\right.$, unless otherwise specified)

| Characteristics |  | Symbol | Test Condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Logic input voltage |  | VIH | Logic input pins | 2.0 | - | 5.0 | V |
|  |  | VIL |  | GND | - | 0.8 |  |
| Input hysteresis voltage |  | $\mathrm{V}_{\text {IN(HYS }}$ ) | Logic input pins (Note) | 100 | 200 | 300 | mV |
| Digital input current | High | $\mathrm{lin}_{(H)}$ | $\mathrm{V}_{\mathrm{IN}}=5 \mathrm{~V}$ at the digital input pins under test | 35 | 50 | 75 | $\mu \mathrm{A}$ |
|  | Low | $1 \mathrm{ln}(\mathrm{L})$ | $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}$ at the digital input pins under test | - | - | 1.0 | $\mu \mathrm{A}$ |
| MO output voltage | High | $\mathrm{V}_{\text {OH(MO) }}$ | $\mathrm{I}_{\mathrm{OH}}=-24 \mathrm{~mA}$ when the output is High | 2.4 | - | - | V |
|  | Low | Vol(mo) | loL $=24 \mathrm{~mA}$ when the output is Low | - | - | 0.5 | V |
| Supply current |  | $\mathrm{I}_{\mathrm{M} 1}$ | Outputs open, In STANDBY mode | - | 2.5 | 3.0 | mA |
|  |  | $\mathrm{I}_{\mathrm{M} 2}$ | Outputs open, ENABLE = Low | - | 4.0 | 5.5 | mA |
|  |  | $\mathrm{I}_{\text {M }}$ | Outputs open (full step) | - | 5 | 7 | mA |
| Output leakage current | High-side | Іон | $\mathrm{V}_{\mathrm{RS}}=\mathrm{V}_{\mathrm{M}}=40 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{A}$ |
|  | Low-side | 1 lo | $\mathrm{V}_{\mathrm{RS}}=\mathrm{V}_{\mathrm{M}}=\mathrm{V}_{\text {OUT }}=40 \mathrm{~V}$ | 1 | - | - | $\mu \mathrm{A}$ |
| Output current difference between channels |  | $\Delta \mathrm{lout1}$ | Output current difference between channels | -5 | 0 | 5 | \% |
| Output current difference relative to the predetermined value |  | $\Delta \mathrm{l}_{\text {OUT2 }}$ | $\mathrm{l}_{\text {OUt }}=1.0 \mathrm{~A}$ | -5 | 0 | 5 | \% |
| Rs pin current |  | IRS | $\begin{aligned} & \mathrm{V}_{\mathrm{RS}}=\mathrm{V}_{\mathrm{M}}=24 \mathrm{~V}, \\ & \text { DMODE_0,1,2 }=\mathrm{L} \\ & \text { ENABLE }=\mathrm{L} \end{aligned}$ | 0 | - | 27.0 | $\mu \mathrm{A}$ |
| Drain-source ON-resistance of the output transistors (upper and lower sum) |  | Ron(D-S) | $\begin{aligned} & \text { lout }=1.0 \mathrm{~A}, \\ & \mathrm{Tj}=25^{\circ} \mathrm{C} \end{aligned}$ | - | 0.8 | 1.2 | $\Omega$ |

Note: VIN (L to H) is defined as the VIN voltage that causes the outputs (OUT_A1, OUT_A2, OUT_B1, and OUT_B2 pin) to change when a pin under test is gradually raised from $0 \mathrm{~V} . \mathrm{V}_{\mathrm{IN}(\mathrm{H} \text { to } \mathrm{L})}$ is defined as the $\mathrm{V}_{\text {IN }}$ voltage that causes the outputs (OUT_A1, OUT_A2, OUT_B1, and OUT_B2 pin) to change when the pin is then gradually lowered.
The difference between $\left.\mathrm{V}_{\text {IN }(\mathrm{L} \text { to }} \mathrm{H}\right)$ and $\left.\mathrm{V}_{\text {IN (H to }} \mathrm{L}\right)$ is defined as the input hysteresis.

## 13-2. Electrical Characteristics $2\left(\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{VM}=24 \mathrm{~V}\right.$, unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {ref }}$ input current | $\mathrm{I}_{\text {ref }}$ | $\mathrm{V}_{\text {ref }}=3.0 \mathrm{~V}$ | - | 0 | 1.0 | $\mu \mathrm{~A}$ |
| $\mathrm{~V}_{\text {ref }}$ decay rate | $\mathrm{V}_{\text {ref }}(\mathrm{GAIN})$ | $\mathrm{V}_{\text {ref }}=2.0 \mathrm{~V}$ | $1 / 4.8$ | $1 / 5.0$ | $1 / 5.2$ | - |
| TSD threshold $\quad$ (Note 1)) | $\mathrm{T}_{\mathrm{j}} \mathrm{TSD}$ |  | 140 | 150 | 170 | ${ }^{\circ} \mathrm{C}$ |
| VM recovery voltage | $\mathrm{V}_{\text {MR }}$ |  | 7.0 | 8.0 | 9.0 | V |
| Overcurrent trip threshold(Note 2) | ISD |  | 2.0 | 3.0 | 4.0 | A |
| Power-supply voltage for internal <br> circuit operation | $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{I}_{\mathrm{CC}}=5.0 \mathrm{~mA}$ | 4.75 | 5.0 | 5.25 | V |

Note 1: Thermal shutdown (TSD) circuitry
When the junction temperature of the device reaches the threshold, the TSD circuitry is tripped, causing the internal reset circuitry to turn off the output transistors. The TSD circuitry is tripped at a temperature between $140^{\circ} \mathrm{C}(\mathrm{min})$ and $170^{\circ} \mathrm{C}$ (max). Once tripped, the TSD circuitry keeps the output transistors off until the TSD circuitry is released. The TSD status is released once the TB62269FTAG is rebooted or all the D_MODE pins (DMODE_1,2) are switched to Low (set to STANDBY mode). The TSD circuitry does not necessarily guarantee the complete safety of the device; therefore do not use the TSD circuitry actively.
Note 2: Overcurrent shutdown (ISD) circuitry
When the output current reaches the threshold, the ISD circuitry is tripped, causing the internal reset circuitry to turn off the output transistors. To prevent the ISD circuitry from being tripped owing to switching noise, it has a masking time of four CR oscillator cycles. Once tripped, it takes a maximum of four cycles to exit ISD mode and resume normal operation. The ISD circuitry remains active until all the D_MODE(D_MODE1,2) pins are switched to Low or the TB62269FTAG is rebooted. The TB62269FTAG remains in STANDBY mode while in ISD mode.
Note 3: When the power supply voltage (Vcc) for operating internal circuit is divided by the external resistor and used as Vref input voltage, the accuracy of the output current setting value becomes $\pm 8 \%$ together with the Vcc output voltage accuracy and the Vref decay ratio accuracy.
Note 4: Even when the logic input signal is input under the condition that the VM voltage is not supplied, the electromotive force and the leakage current by the signal input are not generated. However, before VM is rebooted, logic input signal should be controlled not to let the motor operating by rebooting VM.

## Back-EMF

While a motor is rotating, there is a timing at which power is fed back to the power supply. At that timing, the motor current is fed back to the power supply owing to the effect of the motor back-EMF.
If the power supply does not have enough sink capability, the power supply and output pins of the device might rise above the rated voltages. The magnitude of the motor back-EMF varies with usage conditions and motor characteristics. It must be fully verified that there is no risk that the TB62269FTAG or other components will be damaged or fail owing to the motor back-EMF.

## Cautions on Overcurrent Shutdown (ISD) and Thermal Shutdown (TSD)

The ISD and TSD circuits are only intended to provide temporary protection against irregular conditions such as an output short circuit; they do not necessarily guarantee complete IC safety.
If the device is used beyond the specified operating ranges, these circuits may not operate properly: then the device may be damaged owing to an output short circuit.
The ISD circuit is only intended to provide temporary protection against an output short circuit. If such a condition persists for a long time, the device may be damaged owing to overstress. Overcurrent conditions must be removed immediately by external hardware.

## IC Mounting

Do not insert devices in the wrong orientation or incorrectly. Otherwise, it may cause device breakdown, damage and/or deterioration.

13-3. AC Electrical Characteristics ( $\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{VM}=24 \mathrm{~V}, 6.8 \mathrm{mH} / 5.7 \Omega$ )

| Characteristics |  | Symbol | Test Condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Logic input frequency |  | fLogic | OSC= 1600 kHz | 1.0 | - | 150 | kHz |
| Width of minimum clock pulse | High | $\mathrm{T}_{\text {CLK(H) }}$ | - | 300 | - | - | ns |
|  | Low | $\mathrm{T}_{\text {CLK }(L)}$ | - | 250 | - | - |  |
| Output transistor Switching characteristic |  | tr | - | 0.15 | 0.20 | 0.25 | $\mu \mathrm{S}$ |
|  |  | tf | - | 0.12 | 0.15 | 0.18 |  |
|  |  | tpLH(CLK) | CLK Signal to OUT | - | 1.0 | - |  |
|  |  | tpHL(CLK) | CLK Signal to OUT | - | 1.5 | - |  |
| Blanking time for current spike prevention |  | tBLANK | lout $=1.0 \mathrm{~A}$ | 450 | 700 | 950 | ns |
| OSC_M oscillation frequency |  | fosc | $\begin{gathered} \mathrm{C}_{\text {osc }}=270 \mathrm{pF}, \\ \mathrm{R}_{\mathrm{osc}}=3.6 \mathrm{k} \Omega \end{gathered}$ | 1200 | 1600 | 2000 | kHz |
| Chopper frequency range |  | fchop(Typ.) | Output operation (lout $=1.0 \mathrm{~A}$ ) | 40 | 100 | 150 | kHz |
| Chopper setting frequency |  | fchop | $\begin{gathered} \text { Output operation (lout }=1.0 \mathrm{~A}) \\ \text { OSC }=\text { For } 1600 \mathrm{kHz} \end{gathered}$ | - | 100 | - | kHz |
| ISD masking time |  | tISD(Mask) | After ISD threshold is exceeded owing to an output short circuit to power or ground | - | 4 | - | $\begin{gathered} \text { CR-C } \\ \text { LK } \end{gathered}$ |
| ISD on-time |  | tISD |  | - | - | 8 |  |

Timing Charts of Output Transistors Switching
Timing charts may be simplified for explanatory purposes.


Figure 1 Timing Charts of Output Transistors Switching

## 14. Mixed Decay Mode /Detecting zero point



The NF point shows that the output current reaches the setting current value. The Charge time shows the difference value according to the characteristic(such as inductance or resistance) of step resolutions.


Note: When Iout reaches the 0A level, the output transistor will turn to " $\mathrm{Hi}-\mathrm{Z}$ " status.

## 15. Output Transistor Operating Modes



Charge Mode A current flows into the motor coil.


Slow Mode
A current circulates around the motor coil and this device.


Fast Mode
The energy of the motor coil is fed back to the power
16. Output Transistor Operating Functions

| CLK | U1 | U2 | L1 | L2 |
| :---: | :---: | :---: | :---: | :---: |
| Charge mode | ON | OFF | OFF | ON |
| Slow mode | OFF | OFF | ON | ON |
| Fast mode | OFF | ON | ON | OFF |

Note: This table shows an example of when the current flows as indicated by the arrows in the figures shown above. If the current flows in the opposite direction, refer to the following table.

| CLK | U1 | U2 | L1 | L2 |
| :---: | :---: | :---: | :---: | :---: |
| Charge mode | OFF | ON | ON | OFF |
| Slow mode | OFF | OFF | ON | ON |
| Fast mode | ON | OFF | OFF | ON |

The TB62269FTAG switches among Charge, Slow-Decay and Fast-Decay modes automatically for constant-current control.

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

## 17. Calculation of the Setting Output Current

For PWM constant-current control, the TB62269FTAG uses a clock generated by the CR oscillator. The peak output current can be set via the current-sensing resistor (RS) and the reference voltage ( $\mathrm{V}_{\text {ref }}$ ), as follows:


Vref(gain): Vref decay ratio is $1 / 5.0$ (typ.).
Ex.): In case of $100 \%$ setting,
When Vref $=3.0$ V, Torque $=100 \%$, and $R S=0.51 \Omega$,
constant current output of the motor (peak current) is calculated as follows;

$$
\mathrm{I}_{\text {out }}=3.0 \mathrm{~V} / 5.0 / 0.51 \Omega=1.18 \mathrm{~A} .
$$

## 18. Calculation of the OSCM oscillation frequency (chopper reference frequency)

OSCM oscillation frequency (fOSCM) and chopper frequency (fchop) are computable in the following expressions.
$\mathrm{fOSCM}=1 /[0.56 \mathrm{x}\{\mathrm{Cx}(\mathrm{R} 1+500)\}] \ldots . . \mathrm{C}, \mathrm{R} 1$ : External constant for OSCM $(\mathrm{C}=270 \mathrm{pF}, \mathrm{R} 1=3.6 \mathrm{k} \Omega)$
fchop $=$ fOSCM $/ 16$
Because the loss of the gate in IC rises, generation of heat grows though wavy reproducibility goes up because the pulsating flow of the current decreases when the chopper frequency is raised.

There is a possibility of the current pulsating flow increasing though a decrease in generation of heat can be expected by lowering the chopper frequency.
The thing set within the range of the frequency from 50 to about 100 kHz based on the frequency generally of about 70 kHz is recommended.

## 19. IC Power Consumption

The power consumed by the TB62269FTAG is approximately the sum of the following; 19-1 Power consumption of output transistors, and 19-2 Power consumption of logic block and IM domain.

## 19-1. Power consumption of output transistors using the $\mathrm{R}_{\mathrm{on}}$ (upper + lower) value of $1.0 \Omega$

The power of the output transistors is consumed by upper and lower H -bridge.
The power consumed by each H -bridge is given by:

$$
\begin{equation*}
\mathrm{P}(\text { out })=\operatorname{Iout}(\mathrm{A}) \times \operatorname{VDS}(\mathrm{V})=\operatorname{Iout}(\mathrm{A})^{2} \times \operatorname{Ron}(\Omega) \tag{1}
\end{equation*}
$$

In full step mode (in which two phases have a phase difference of $90^{\circ}$ ), the average power consumption in the output transistors is calculated as follows:

```
Ron = 1.0\Omega, Iout (peak: Max)=1.0 A, VM = 24 V
P}(\mathrm{ out ) = 2(Tr) }\times1.0(\textrm{A}\mp@subsup{)}{}{2}\times1.0(\Omega
    = 2.0 (W)
```


## 19-2. Power consumption of logic block and IM domain

The power consumption of logic block and the IM domain is calculated separately for normal operation and standby modes.

$$
\begin{array}{ll}
\text { I (IM3) }=5 \mathrm{~mA} \text { (typ.) } & : \text { Normal operation mode/1axis } \\
\text { I (IM2) }=3.5 \mathrm{~mA} \text { (typ.) } & \text { : STANDBY mode }
\end{array}
$$

The output domain is connected to $\mathrm{VM}(24 \mathrm{~V})$. It consists of the digital logic connected to $\mathrm{VM}(24 \mathrm{~V})$ and the network affected by the switching of the output transistors.

The total power consumed by IM can be estimated as:

```
P}(\textrm{IM})=24(V)\times0.005(A
\[
\begin{equation*}
=0.12(\mathrm{~W}) \tag{3}
\end{equation*}
\]
```


## 19-3. Power consumption

Hence, the total power consumption of the TB62269FTAG is:

$$
\mathrm{P}=\mathrm{P}(\text { out })+\mathrm{P}(\mathrm{IM})=2.12(\mathrm{~W})
$$

The STANDBY mode power consumption per axis is given by:
$\mathrm{P}(\mathrm{STANDBY}$ mode $)=24(\mathrm{~V}) \times 0.0035(\mathrm{~A})=0.084(\mathrm{~W})$

Board design should be fully verified, taking thermal dissipation into consideration.

## 20. Step Resolution Drive



MO output is the waveform in the state of pull-up.

## 21. Electrical Angle of Step Resolution Mode and Initialize Position

- Full step resolution mode

- Half step resolution mode

- Quarter Step resolution mode


Half Step resolution (b)




1/16 Step resolution

## CLK

100\%



$$
\%
$$

## 1/32 Step resolution






IB(\%)


IA(\%)

## 22. Package Dimensions

P-VQFN32-0505-0.50-004


## Notes on Contents

(1) Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.
(2) Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.
(3) Timing Charts

Timing charts may be simplified for explanatory purposes.
(4) Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass-production design stage
Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.
(5) Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment

## IC Usage Considerations

## Notes on handling of ICs

(1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.
(2) Do not insert devices in the wrong orientation or incorrectly. Make sure that the positive and negative terminals of power supplies are connected properly.
Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.
In addition, do not use any device inserted in the wrong orientation or incorrectly to which current is applied even just once.
(3) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in the case of overcurrent and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead to smoke or ignition. To minimize the effects of the flow of a large current in the case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
(4) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition. Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
(5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator.
If there is a large amount of leakage current such as from input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure may cause smoke or ignition. (The overcurrent may cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection-type IC that inputs output DC voltage to a speaker directly.

## Points to remember on handling of ICs

## Overcurrent detection Circuit

Overcurrent detection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the overcurrent detection circuits operate against the overcurrent, clear the overcurrent status immediately.
Depending on the method of use and usage conditions, exceeding absolute maximum ratings may cause the overcurrent detection circuit to operate improperly or IC breakdown may occur before operation. In addition, depending on the method of use and usage conditions, if overcurrent continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

Thermal Shutdown Circuit
Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over-temperature, clear the heat generation status immediately.
Depending on the method of use and usage conditions, exceeding absolute maximum ratings may cause the thermal shutdown circuit to operate improperly or IC breakdown to occur before operation.

## Heat Radiation Design

When using an IC with large current flow such as power amp, regulator or driver, design the device so that heat is appropriately radiated, in order not to exceed the specified junction temperature (TJ) at any time or under any condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, when designing the device, take into consideration the effect of IC heat radiation with peripheral components.

## Back-EMF

When a motor rotates in the reverse direction, stops or slows abruptly, current flows back to the motor's power supply owing to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond the absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

## RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY ANDIOR RELIABILITY, ANDIOR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE ANDIOR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.


## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Motor/Motion/Ignition Controllers \& Drivers category:
Click to view products by Toshiba manufacturer:

Other Similar products are found below :
FSB50550TB2 FSBF15CH60BTH MSVCPM2-63-12 MSVGW45-14-2 MSVGW54-14-3 MSVGW54-14-5 NTE7043 LA6565VR-TLM-E LB11650-E LB1837M-TLM-E LB1845DAZ-XE LC898300XA-MH SS30-TE-L-E 26700 LV8281VR-TLM-H BA5839FP-E2 IRAM2361067A LA6584JA-AH LB11847L-E NCV70501DW002R2G AH293-PL-B STK672-630CN-E TND315S-TL-2H FNA23060 FSB50250AB FNA41060 MSVB54 MSVBTC50E MSVCPM3-54-12 MSVCPM3-63-12 MSVCPM4-63-12 MSVTA120 FSB50550AB NCV70501DW002G LC898301XA-MH LV8413GP-TE-L-E MSVGW45-14-3 MSVGW45-14-4 MSVGW45-14-5 MSVGW54-14-4 STK984-091A-E MP6519GQ-Z LB11651-E IRSM515-025DA4 LV8127T-TLM-H MC33812EKR2 NCP81382MNTXG TDA21801

LB11851FA-BH NCV70627DQ001R2G


[^0]:    Note: Please be careful about thermal conditions during use.

